NSN 5961-00-192-6230

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View Online at https://aerobasegroup.com/nsn/5961-00-192-6230 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 collector to base voltage/static/emitter open and 55.0 collector to emitter voltage/static/base open and 15.0 emitter to base voltage, static, collector open and 90.0 collector-to-emitter, with voltage between base and emitter and 60.0 collector-to-emitter substaining voltage, resistance between base and emitter **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-0581 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: